TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSIII)

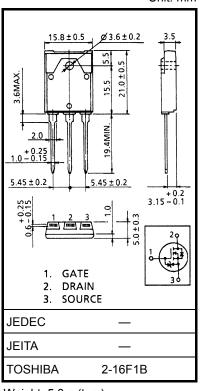
2SK3017

DC–DC Converter, Relay Drive and Motor Drive Applications

- Low drain-source ON resistance : $R_{DS (ON)} = 1.05 \Omega$ (typ.)
- High forward transfer admittance : |Y_{fs}| = 7.0 S (typ.)
 - Low leakage current : $I_{DSS} = 100 \ \mu A \ (max) \ (V_{DS} = 720 \ V)$
- Enhancement mode : $V_{th} = 2.0$ to $4.0 \text{ V} (V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	900	V
Drain-gate voltage (R	_{GS} = 20 kΩ)	V _{DGR}	900	V
Gate-source voltage		V _{GSS}	±30	V
Drain current	DC (Note 1)	I _D	8.5	A
	Pulse (Note 1)	I _{DP}	25.5	А
Drain power dissipation	n (Tc = 25°C)	PD	90	W
Single pulse avalanche	e energy (Note 2)	E _{AS}	966	mJ
Avalanche current		I _{AR}	8.5	А
Repetitive avalanche e	nergy (Note 3)	E _{AR}	9	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature ra	ange	T _{stg}	-55 to 150	°C



Weight: 5.8 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch−c)}	1.39	°C / W
Thermal resistance, channel to ambient	R _{th (ch−a)}	41.6	°C / W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 24.5 mH, R_G = 25 Ω , I_{AR} = 8.5 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution. Unit: mm

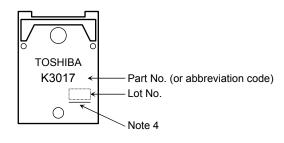
Electrical Characteristics (Ta = 25°C)

Charao	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	Pakage current I_{GSS} $V_{GS} = \pm 30 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$		_	—	±10	μA	
Gate-source bro	eakdown voltage	V (BR) GSS	I _G = ±10 μA, V _{DS} = 0 V	±30	_	_	V
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = 720 V, V _{GS} = 0 V		_	100	μA
Drain-source br	eakdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	900	_	_	V
Gate threshold v	voltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0	_	4.0	V
Drain-source O	N resistance	R _{DS (ON)}	V _{GS} = 10 V, I _D = 4 A		1.05	1.25	Ω
Forward transfe	r admittance	Y _{fs}	V _{DS} = 15 V, I _D = 4 A	3.5	7.0		S
Input capacitance	apacitance C _{iss}				2150		pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	35		
Output capacitance		Coss			220		
Switching time	Rise time	tr	$V_{GS} \stackrel{10 \text{ V}}{}_{0 \text{ V}} \prod_{\substack{O \text{ V} \\ \downarrow \downarrow \downarrow \\ \downarrow \downarrow \downarrow \downarrow \\ \downarrow \downarrow \downarrow \downarrow \downarrow \\ \downarrow \downarrow$	_	25	_	
	Turn-on time	t _{on}		_	60	_	
	Fall time	t _f		_	25		- ns
	Turn-off time	t _{off}	Duty $\leq 1\%$, t _w = 10 µs	_	120		
Total gate charge (Gate-source plus gate-drain)		Qg		_	70	_	
Gate-source charge		Q _{gs}	V _{DD} ≈ 400 V, V _{GS} = 10 V, I _D = 8 A		37	—	nC
Gate-drain ("miller") charge		Q _{gd}			33	_	

Source–Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	8.5	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_		25.5	А
Forward voltage (diode)	V _{DSF}	I _{DR} = 8.5 A, V _{GS} = 0 V			-1.9	V
Reverse recovery time	t _{rr}	I _{DR} = 8.5 A, V _{GS} = 0 V		1300		ns
Reverse recovery charge	Q _{rr}	dI _{DR} / dt = 100 Å / µs		14.5	_	μC

Marking

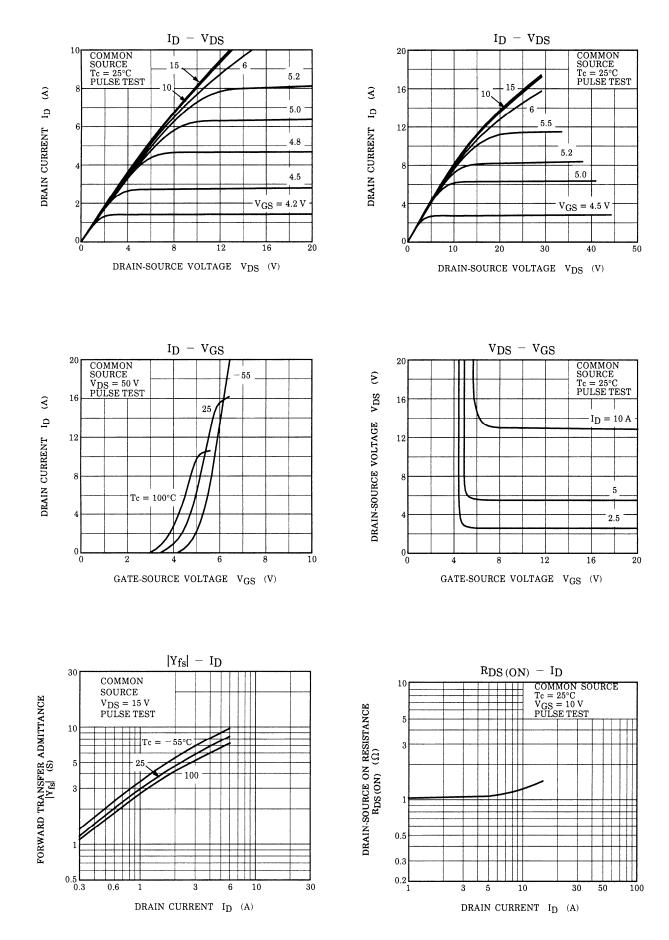


Note 4: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV

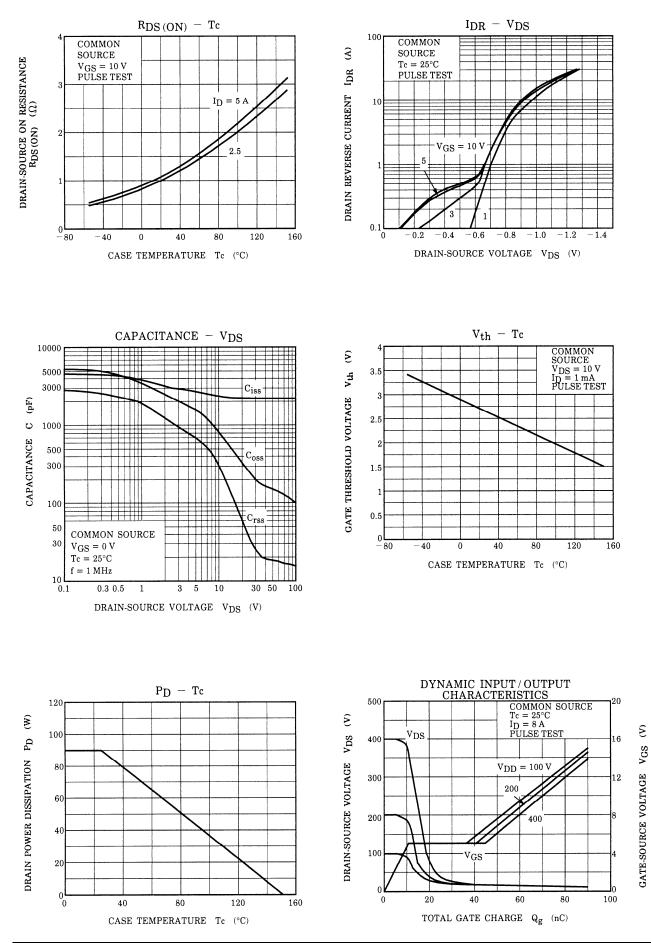
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]] Please contact your TOSHIBA sales representative for details as to

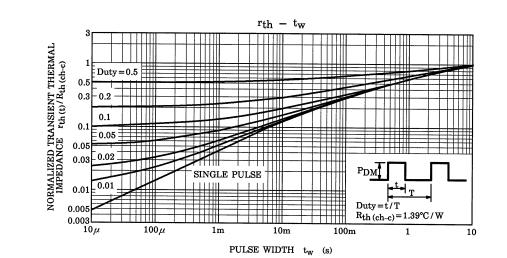
environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

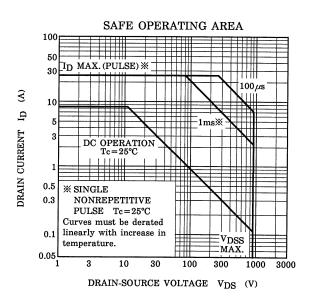
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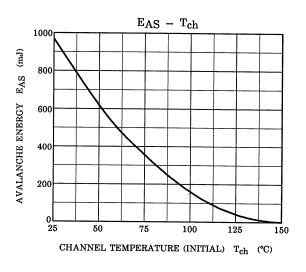


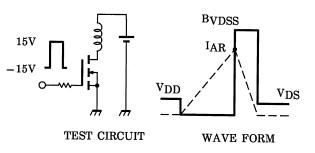
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